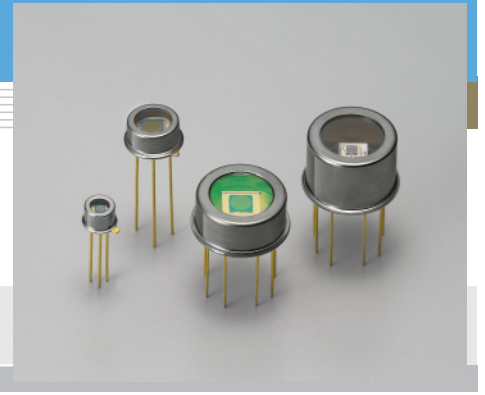


InGaAs PIN photodiode G8422/G8372/G5852 series

Long wavelength type (up to 2.1 μm)



Features

- Cut-off wavelength: 2.1 μm
- 3-pin TO-18 package: low price
- TE-cooled type TO-8 package: low dark current
- Active area: $\phi 0.3$ to $\phi 3$ mm

Applications

- Gas analyzer
- Water content analyzer
- NIR (Near Infrared) photometry

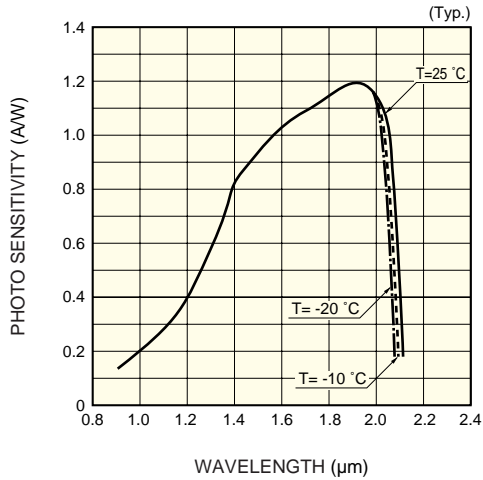
Specifications / Absolute maximum ratings

Type No.	Dimensional outline	Package	Cooling	Active area (mm)	Absolute maximum ratings				
					Thermistor power dissipation (mW)	TE-cooler allowable current (A)	Reverse voltage V_R (V)	Operating temperature T_{opr} ($^{\circ}\text{C}$)	Storage temperature T_{stg} ($^{\circ}\text{C}$)
G8422-03	①	TO-18	Non-cooled	$\phi 0.3$	-	-	-	-40 to +85	-55 to +125
G8422-05				$\phi 0.5$					
G8372-01				$\phi 1$					
G8372-03				$\phi 3$					
G5852-103	③	TO-8	One-stage TE-cooled	$\phi 0.3$	0.2	1.5	2	-40 to +70	-55 to +85
G5852-11				$\phi 1$					
G5852-13				$\phi 3$					
G5852-203				$\phi 0.3$					
G5852-21	④	TO-8	Two-stage TE-cooled	$\phi 0.3$	0.2	1.0	-	-	-
G5852-23				$\phi 1$					
G5852-23				$\phi 3$					

Electrical and optical characteristics (Typ. unless otherwise noted)

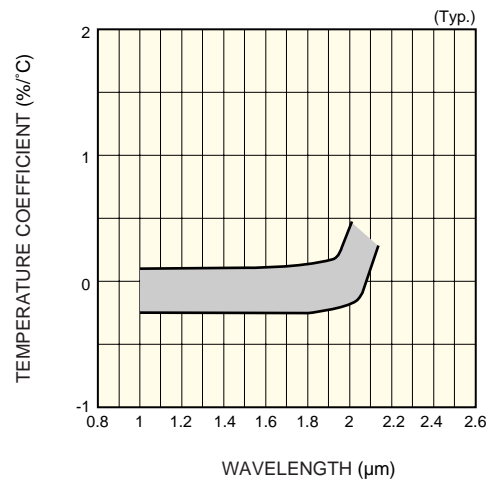
Type No.	Measurement condition	Spectral response range λ (μm)	Peak sensitivity wavelength λ_p (μm)	Photo sensitivity $S_{\lambda=\lambda_p}$ (A/W)	Dark current I_D ($V_R=1$ V)		Cut-off frequency f_c ($V_R=1$ V, $R_L=50$ Ω) (MHz)	Terminal capacitance C_t ($V_R=1$ V, $f=1$ MHz) (pF)	Shunt resistance R_{sh} ($V_R=10$ mV) (M Ω)	D^* $\lambda=\lambda_p$ (cm \cdot Hz $^{1/2}$ /W)	NEP $\lambda=\lambda_p$ (W/Hz $^{1/2}$)	
	Element Temperature T ($^{\circ}\text{C}$)				Typ. (nA)	Max. (nA)						
	G8422-03				25	0.9 to 2.1						1.95
G8422-05		125	1250	80	20		0.3	2.5×10^{-13}				
G8372-01		500	5000	40	80		0.1	4×10^{-13}				
G8372-03		5 (μA)	50 (μA)	3	800		0.01	1.5×10^{-12}				
G5852-103	-10	0.9 to 2.07	1.95	1.2	5.5	55	100	8	9	8×10^{11}	5×10^{-14}	
G5852-11						50	500	40	80		1	1×10^{-13}
G5852-13						500	5000	3	800		0.1	4×10^{-13}
G5852-203	-20	0.9 to 2.05	1.95	1.2	3	30	100	8	18	1.2×10^{12}	3×10^{-14}	
G5852-21						25	250	40	80		2	8×10^{-14}
G5852-23						250	2500	3	800		0.2	3×10^{-13}

■ Spectral response



KIRDB0226EA

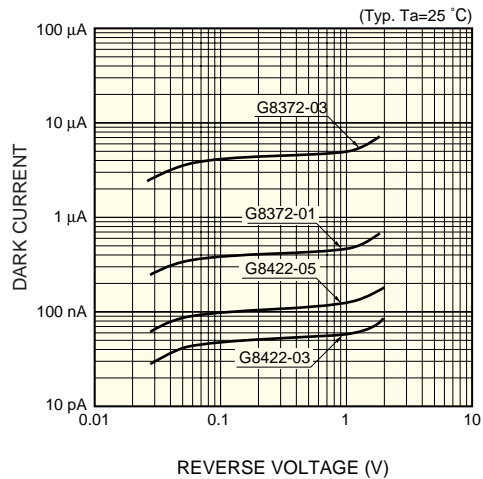
■ Photo sensitivity temperature characteristic



KIRDB0207EA

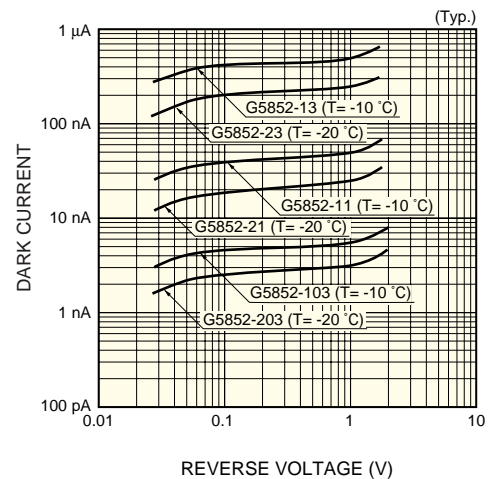
■ Dark current vs. reverse voltage

Non-cooled type



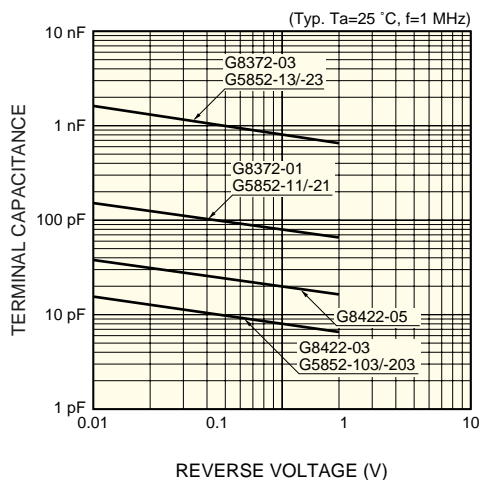
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TE-cooled type



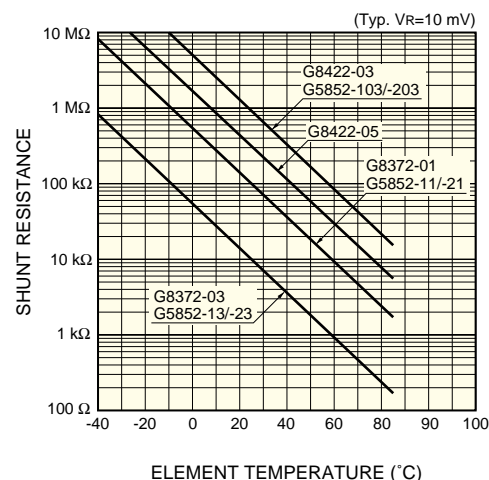
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■ Terminal capacitance vs. reverse voltage



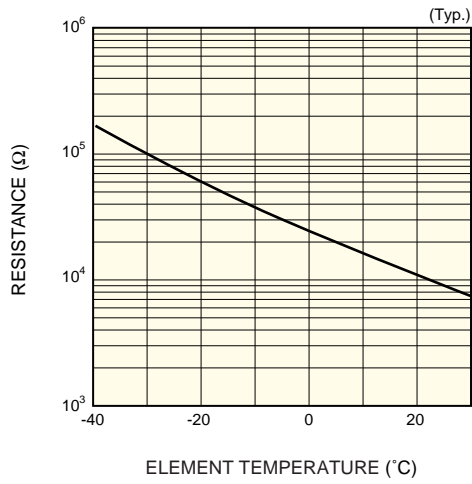
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■ Shunt resistance vs. element temperature



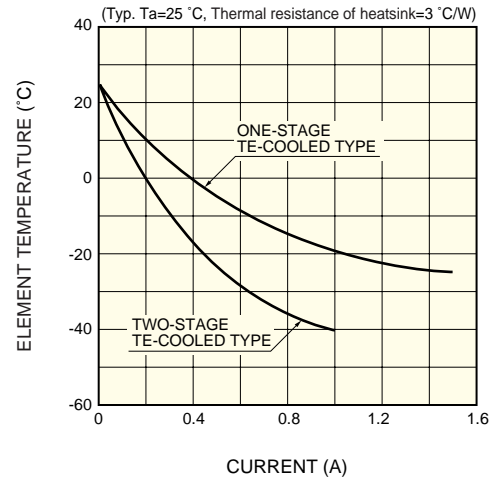
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■ Thermistor temperature characteristic



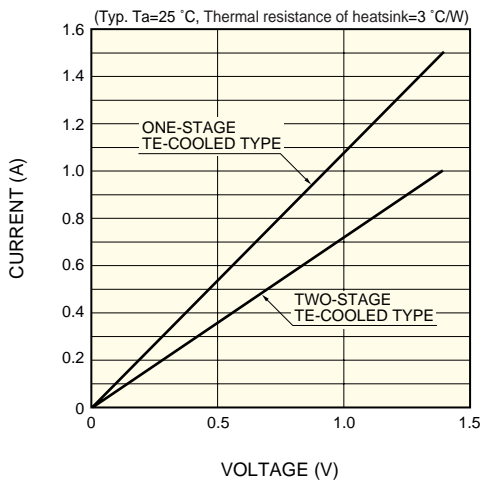
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■ Cooling characteristics of TE-cooler



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■ Current vs. voltage characteristics of TE-cooler

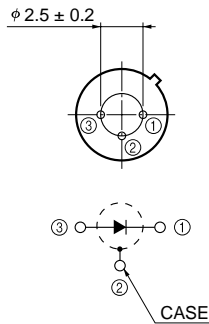
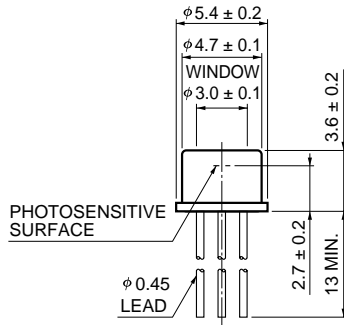


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InGaAs PIN photodiode G8422/G8372/G5852 series

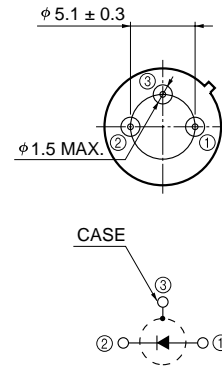
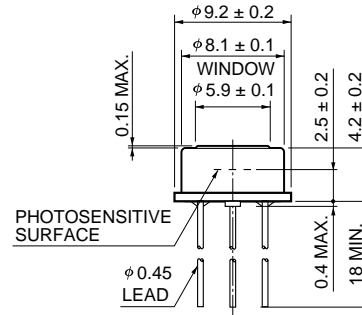
Dimensional outline (unit: mm)

① G8422-03/-05, G8372-01



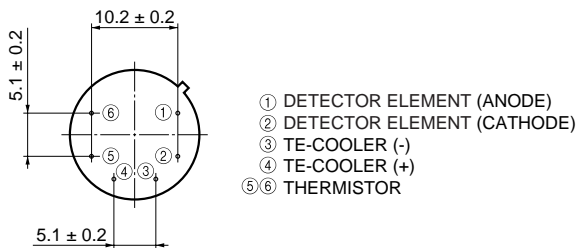
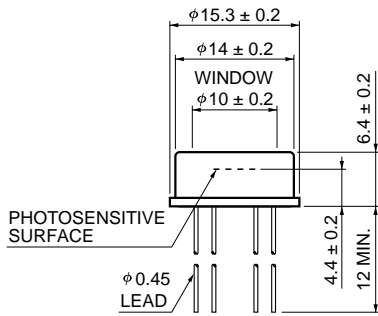
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② G8372-03



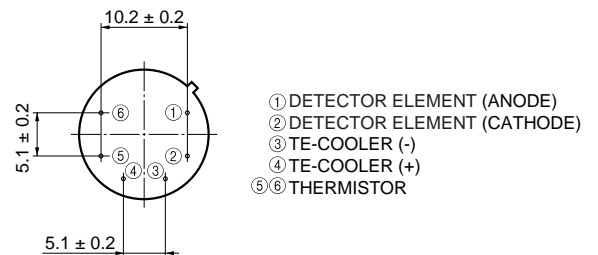
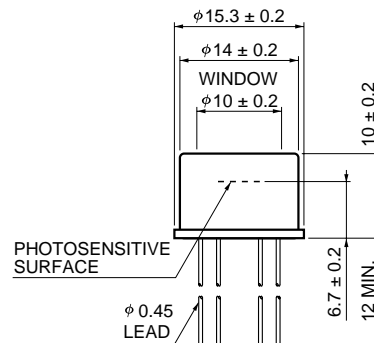
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③ G5852-103/-11/-13



KIRDA0029EB

④ G5852-203/-21/-23



KIRDA0031EB

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